General Description

The MAX3030E–MAX3033E family of quad RS-422 transmitters send digital data transmission signals over twisted-pair balanced lines in accordance with TIA/EIA-422-B and ITU-T V.11 standards. All transmitter outputs are protected to ±15kV using the Human Body Model. The MAX3030E–MAX3033E are available with either a 2Mbps or 20Mbps guaranteed baud rate. The 2Mbps baud rate transmitters feature slew-rate-limiting to minimize EMI and reduce reflections caused by improperly terminated cables.

The 20Mbps baud rate transmitters feature low-static current consumption (I_{CC} < 100 μ A), making them ideal for battery-powered and power-conscious applications. They have a maximum propagation delay of 16ns and a part-to-part skew less than 5ns, making these devices ideal for driving parallel data. The MAX3030E–MAX3033E feature hot-swap capability that eliminates false transitions on the data cable during power-up or hot insertion.

The MAX3030E–MAX3033E are low-power, ESD-protected, pin-compatible upgrades to the industry-standard 26LS31 and SN75174. They are available in space-saving 16-pin TSSOP and SO packages.

Applications

_Features

- Meet TIA/EIA-422-B (RS-422) and ITU-T V.11 Recommendation
- ±15kV ESD Protection on Tx Outputs
- Hot-Swap Functionality
- Guaranteed 20Mbps Data Rate (MAX3030E, MAX3032E)
- Slew-Rate-Controlled 2Mbps Data Rate (MAX3031E, MAX3033E)
- Available in 16-Pin TSSOP and Narrow SO Packages
- ♦ Low-Power Design (<330µW, V_{CC} = 3.3V Static)

TEMP RANGE

0°C to +70°C

0°C to +70°C

-40°C to +85°C

-40°C to +85°C

0°C to +70°C

0°C to +70°C

-40°C to +85°C

-40°C to +85°C

0°C to +70°C

0°C to +70°C

-40°C to +85°C

-40°C to +85°C

0°C to +70°C

0°C to +70°C

-40°C to +85°C

-40°C to +85°C

- +3.3V Operation
- Industry-Standard Pinout
- Thermal Shutdown

PART

MAX3030ECSE

MAX3030ECUE

MAX3030EESE

MAX3030EEUE

MAX3031ECSE

MAX3031ECUE

MAX3031EESE

MAX3031EEUE

MAX3032ECSE

MAX3032ECUE

MAX3032EESE

MAX3032EEUE

MAX3033ECSE

MAX3033ECUE

MAX3033EESE

MAX3033EEUE

Pin Con • VIEW DI1 1 0 16 Vcc DI1 1

Telecom Backplanes

V.11/X.21 Interface

Industrial PLCs

Motor Control



M/IXI/M

_ Maxim Integrated Products 1

Ordering Information

PIN-PACKAGE

16 SO (Narrow)

16 TSSOP

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Pin Configurations

ABSOLUTE MAXIMUM RATINGS

(All Voltages Are Referenced to Device Ground, Unless Otherwise Noted)

V _{CC} +6V
EN1&2, EN3&4, EN, EN0.3V to +6V
DI0.3V to +6V
DO_+, DO (normal condition)0.3V to (V _{CC} + 0.3V)
DO_+, DO (power-off or three-state condition)0.3V to +6V
Driver Output Current per Pin±150mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
16-Pin SO (derate 8.70mW/°C above +70°C)696mW	/
16-Pin TSSOP (derate 9.40mW/°C above +70°C)755mW	/
Operating Temperature Ranges	
MAX303_EC0°C to +70°C	;
MAX303_EE40°C to +85°C	;
Junction Temperature+150°C	;
Storage Temperature Range65°C to +160°C	;
Lead Temperature (soldering, 10s)+300°C	;

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(3V \le V_{CC} \le 3.6V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	PARAMETER SYMBOL CONDITIONS			ТҮР	MAX	UNITS
DRIVER OUTPUT: DO_+, DO						
	VOD1	$R_L = 100\Omega$, Figure 1	2.0			
Differential Driver Output	V _{OD2}	R _L = ∞, Figure 1			3.6	v
Differential Driver Output	V _{OD3}	R_L = 3.9k Ω (for compliance with V.11), Figure 1			3.6	v
Change in Differential Output Voltage	ΔV _{OD}	R _L = 100Ω (Note 2)	-0.4		+0.4	V
Driver Common-Mode Output Voltage	Voc	$R_L = 100\Omega$, Figure 1			3	V
Change in Common-Mode Voltage	ΔV _{OC}	R _L = 100Ω (Note 2)	R _L = 100Ω (Note 2) -0.4		+0.4	V
Three-State Leakage Current	I _{OZ}	V _{OUT} = V _{CC} or GND, driver disabled			±10	μA
Output Leakage Current	IOFF	V _{CC} = 0V, V _{OUT} = 3V or 6V			20	μA
Driver Output Short-Circuit Current	I _{SC}	$V_{OUT} = 0V, V_{IN} = V_{CC} \text{ or } GND$ -150			mA	
INPUTS: EN, EN, EN1&2, EN3&4	ļ		•			
Input High Voltage	VIH		2.0			V
Input Low Voltage	VIL				0.4	V
Input Current	I _{LEAK}				±2	μΑ
Hot-Swap Driver Input Current	I HOTSWAP	EN, EN, EN1&2, EN3&4 (Note 4)			±200	μA
SUPPLY CURRENT						
Supply Current	Icc	No load			100	μΑ
THERMAL PROTECTION						
Thermal-Shutdown Threshold	T _{SH}			160		°C
Thermal-Shutdown Hysteresis				10		°C
ESD Protection DO_		Human Body Model		±15		kV

SWITCHING CHARACTERISTICS—MAX3030E, MAX3032E

 $(3V \le V_{CC} \le 3.6V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
Driver Propagation Delay Low to High	^t DPLH			8	16	
Driver Propagation Delay High to Low	^t DPHL	$R_L = 100\Omega$, $C_L = 50pF$, Figures 2, 3		0	10	ns
Differential Transition Time, Low to High	t _R	$R_L = 100\Omega$, $C_L = 50pF$ (10% to 90%),			10	20
Differential Transition Time, High to Low	t⊨	Figures 2, 3			10	ns
Differential Skew (Same Channel) ItDPLH - tDPHLI	tsK1				±2	20
Skew Driver to Driver (Same Device)	tsk2	$R_L = 100$ Ω, $C_L = 50$ pF, $V_{CC} = 3.3$ V			±Ζ	ns
Skew Part to Part	tsкз	$\label{eq:RL} \begin{split} &R_L = 100\Omega, C_L = 50 pF, V_{CC} = 3.3 V, \\ &\Delta T_{MAX} = +5^\circ C \end{split}$	50pF, V _{CC} = 3.3V,		5	ns
Maximum Data Rate			20			Mbps
Driver Enable to Output High	^t DZH	S2 closed, $R_L = 500\Omega$, $C_L = 50pF$, Figures 4, 5		50	ns	
Driver Enable to Output Low	tdzl	S1 closed, $R_L = 500\Omega$, $C_L = 50pF$, Figures 4, 5		50	ns	
Driver Disable Time from Low	tdlz	S1 closed, $R_L = 500\Omega$, $C_L = 50pF$, Figures 4, 5		50	ns	
Driver Disable Time from High	t _{DHZ}	S2 closed, R _L = 500 Ω , C _L = 50pF, Figures 4, 5	50		50	ns

SWITCHING CHARACTERISTICS—MAX3031E, MAX3033E

 $(3V \le V_{CC} \le 3.6V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Driver Propagation Delay Low to High	t _{DPLH}			40	70	
Driver Propagation Delay High to Low	t _{DPHL}	$R_L = 100\Omega$, $C_L = 50pF$, Figures 2, 3		40	70	ns
Differential Transition Time, Low to High	t _R	$R_L = 100\Omega$, $C_L = 50pF$ (10% to 90%),	15		50	
Differential Transition Time, High to Low	t⊨	Figures 2, 3	15		50	ns
Differential Skew (Same Channel) ItDPLH - tDPHLI	tsK1				. 10	
Skew Driver to Driver (Same Device)	tsk2	$R_L = 100$ Ω, $C_L = 50$ pF, $V_{CC} = 3.3$ V			±10	ns

MAX3030E-MAX3033E

SWITCHING CHARACTERISTICS—MAX3031E, MAX3033E (continued)

 $(3V \le V_{CC} \le 3.6V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $V_{CC} = +3.3V$ and $T_A = +25^{\circ}C$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Skew Part to Part	tsкз	$\label{eq:RL} \begin{split} R_{L} &= 100\Omega, \ C_{L} = 50 pF, \ V_{CC} = 3.3 V, \\ \Delta T_{MAX} &= +5^{\circ} C \end{split}$			18	ns
Maximum Data Rate			2			Mbps
Driver Enable to Output High	^t DZH	S2 closed, R _L = 500 Ω , C _L = 50pF, Figures 4, 5			100	ns
Driver Enable to Output Low	tdzl	S1 closed, R _L = 500 Ω , C _L = 50pF, Figures 4, 5			100	ns
Driver Disable Time from Low	tdlz	S1 closed, R _L = 500 Ω , C _L = 50pF, Figures 4, 5			150	ns
Driver Disable Time from High	tDHZ	S2 closed, R _L = 500 Ω , C _L = 50pF, Figures 4, 5			150	ns

Note 1: All currents into the device are positive; all currents out of the device are negative. All voltages are referenced to device ground, unless otherwise noted.

Note 2: ΔV_{OD} and ΔV_{OC} are the changes in V_{OD} and V_{OC} , respectively, when DI changes state.

Note 3: Only one output shorted at a time.

Note 4: This input current is for the hot-swap enable (EN_, EN, EN) inputs and is present until the first transition only. After the first transition, the input reverts to a standard high-impedance CMOS input with input current I_{LEAK}.

(V_{CC} = +3.3V and T_A = $+25^{\circ}$ C, unless otherwise noted.)



Typical Operating Characteristics

Typical Operating Characteristics (continued)



(V_{CC} = +3.3V and T_A = +25°C, unless otherwise noted.)

M/IXI/N

Typical Operating Characteristics (continued)

(V_{CC} = +3.3V and T_A = +25°C, unless otherwise noted.)





Pin Description

PI	N					
MAX3030E/ MAX3031E	MAX3032E/ MAX3033E	NAME	FUNCTION			
1, 7, 9, 15	1, 7, 9, 15	DI1, DI2, DI3, DI4	Transmitter Inputs. When the corresponding transmitter is enabled, a low on DI_ forces the noninverting output low and inverting output high. Similarly, a high on DI_ forces noninverting output high and inverting output low.			
2, 6, 10, 14	2, 6, 10, 14	DO1+, DO2+, DO3+, DO4+	Noninverting RS-422 Outputs			
3, 5, 11, 13	3, 5, 11, 13	DO1-, DO2-, DO3-, DO4-	Inverting RS-422 Outputs			
4	_	EN	Transmitter Enable Input: Active HIGH. Drive EN HIGH to enable all transmitters. Whe EN is HIGH, drive EN LOW to disable (three-state) all the transmitters. The transmitte outputs are high impedance when disabled. EN is hot-swap protected (see the <i>Hot Swap</i> section).			
8	8	GND	Ground			
12	_	ĒN	Transmitter Enable Input: Active LOW. Drive \overline{EN} LOW to enable all transmitters. When EN is LOW, drive \overline{EN} HIGH to disable all the transmitters. The transmitter outputs are high impedance when disabled. \overline{EN} is hot-swap protected (see the <i>Hot Swap</i> section).			
_	4	EN1&2	Transmitter Enable Input for Channels 1 and 2. Drive EN1&2 HIGH to enable the corresponding transmitters. Drive EN1&2 LOW to disable the corresponding transmitters. The transmitter outputs are high impedance when disabled. EN1&2 is hot-swap protected (see the <i>Hot Swap</i> section).			
_	12	EN3&4	Transmitter Enable Input for Channels 3 and 4. Drive EN3&4 HIGH to enable the corresponding transmitters. Drive EN3&4 LOW to disable the corresponding transmitters. The transmitter outputs are high impedance when disabled. EN3&4 is hot-swap protected (see the <i>Hot Swap</i> section).			
16	16	V _{CC}	Positive Supply; +3V \leq V _{CC} \leq +3.6V. Bypass V _{CC} to GND with a 0.1µF capacitor.			



Figure 1. Differential Driver DC Test Circuit



Figure 3. Differential Driver Propagation Delay and Transition Waveform



Figure 5. Driver Enable/Disable Waveform

Test Circuits and Timing Diagrams



Figure 2. Differential Driver Propagation Delay and Transition Time Test Circuit



Figure 4. Driver Enable/Disable Delays Test Circuit



Figure 6. Short-Circuit Measurements

Test Circuits and [Timing Diagrams (continued]



Figure 7. Power-Off Measurements

Detailed Description

The MAX3030E-MAX3033E are high-speed guad RS-422 transmitters designed for digital data transmission over balanced lines. They are designed to meet the requirements of TIA/EIA-422-B and ITU-T V.11. The MAX3030E-MAX3033E are available in two pinouts to be compatible with both the 26LS31 and SN75174 industry-standard devices. Both are offered in 20Mbps and 2Mbps baud rate. All versions feature a low-static current consumption ($I_{CC} < 100 \mu$ A) that makes them ideal for battery-powered and power-conscious applications. The 20Mbps version has a maximum propagation delay of 16ns and a part-to-part skew less than 5ns, allowing these devices to drive parallel data. The 2Mbps version is slew-rate-limited to reduce EMI and reduce reflections caused by improperly terminated cables.

Outputs have enhanced ESD protection providing ± 15 kV tolerance. All parts feature hot-swap capability that eliminates false transitions on the data cable during power-up or hot insertion.

±15kV ESD Protection

As with all Maxim devices, ESD-protection structures are incorporated on all pins to protect against electrostatic discharges encountered during handling and assembly. The driver outputs and receiver inputs have extra protection against static electricity. Maxim's engineers developed state-of-the-art structures to protect these pins against ESD of ± 15 kV without damage. The ESD structures withstand high ESD in all states: normal operation and power-down. After an ESD event, the MAX3030E–MAX3033E keep working without latchup. ESD protection can be tested in various ways; the transmitter outputs of this product family are characterized for protection to ± 15 kV using the Human Body Model. Other ESD test methodologies include IEC10004-2 Contact Discharge and IEC1000-4-2 Air-Gap Discharge (formerly IEC801-2).

ESD Test Conditions

ESD performance depends on a variety of conditions. Contact Maxim for a reliability report that documents test setup, test methodology, and test results.

Human Body Model

Figure 8 shows the Human Body Model, and Figure 9 shows the current waveform it generates when discharged into low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest, which is then discharged into the test device through a $1.5k\Omega$ resistor.



Figure 8. Human Body ESD Test Model



Figure 9. Human Body Current Waveform

Machine Model

The Machine Model for ESD tests all pins using a 200pF storage capacitor and zero discharge resistance. Its objective is to emulate the stress caused by contact that occurs with handling and assembly during manufacturing. Of course, all pins require this protection during manufacturing, not just inputs and outputs. Therefore, after PC board assembly, the Machine Model is less relevant to I/O ports.

Hot Swap

When circuit boards are plugged into a "hot" backplane, there can be disturbances to the differential signal levels that could be detected by receivers connected to the transmission line. This erroneous data could cause data errors to an RS-422 system. To avoid this, the MAX3030E–MAX3033E have hot-swap capable inputs.

When a circuit board is plugged into a "hot" backplane, there is an interval during which the processor is going through its power-up sequence. During this time, the processor's output drivers are high impedance and are unable to drive the enable inputs of the MAX3030E-MAX3033E (EN, EN, EN_) to defined logic levels. Leakage currents from these high-impedance drivers, of as much as 10µA, could cause the enable inputs of the MAX3030E-MAX3033E to drift high or low. Additionally, parasitic capacitance of the circuit board could cause capacitive coupling of the enable inputs to either GND or V_{CC}. These factors could cause the enable inputs of the MAX3030E-MAX3033E to drift to levels that may enable the transmitter outputs. To avoid this problem, the hot-swap input provides a method of holding the enable inputs of the MAX3030E-MAX3033E in the disabled state as V_{CC} ramps up. This hot-swap input is able to overcome the leakage currents and parasitic capacitances that can pull the enable inputs to the enabled state.

Hot-Swap Input Circuitry

In the MAX3030E–MAX3033E, the enable inputs feature hot-swap capability. At the input there are two NMOS devices, M1 and M2 (Figure 10). When V_{CC} is ramping up from zero, an internal 6µs timer turns on M2 and sets the SR latch, which also turns on M1. Transistors M2, a 2mA current sink, and M1, a 100µA current sink, pull EN to GND through a 5.6k Ω resistor. M2 is designed to pull the EN input to the disabled state against an external parasitic capacitance of up to 100pF that is trying to enable the EN input. After 6µs, the timer turns M2 off and M1 remains on, holding the EN input low against three-state output leakages that might enable EN. M1 remains on until an external source overcomes the required input





Figure 10. Simplified Structure of the Driver Enable Pin (EN)



Figure 11. Differential Power-Up Glitch (Hot Swap)

current. At this time the SR latch resets and M1 turns off. When M1 turns off, EN reverts to a standard, high-impedance CMOS input. Whenever V_{CC} drops below 1V, the hot-swap input is reset. The EN1&2 and EN3&4 input structures are identical to the EN input. For the EN input, there is a complementary circuit employing two PMOS devices pulling the EN input to V_{CC}.

Hot-Swap Line Transient

The circuit of Figure 11 shows a typical offset termination used to guarantee a greater than 200mV offset when a line is not driven. The 50pF capacitor repre-

sents the minimum parasitic capacitance that would exist in a typical application. In most cases, more capacitance exists in the system and reduces the magnitude of the glitch. During a "hot-swap" event when the driver is connected to the line and is powered up, the driver must not cause the differential signal to drop below 200mV (Figures 12 and 13).

Operation of Enable Pins

The MAX3030E–MAX3033E family has two enable-functional versions.

The MAX3030E/MAX3031E are compatible with 26LS31, where the two enable signals control all four transmitters (global enable).



Figure 12. Differential Power-Up Glitch (0.1V/µs)

The MAX3032E/MAX3033E are compatible with the SN75174. EN1&2 controls transmitters 1 and 2, and EN 3&4 controls transmitters 3 and 4 (dual enable).

Typical Applications

The MAX3030E–MAX3033E offer optimum performance when used with the MAX3094E/MAX3096 3.3V quad differential line receivers. Figure 14 shows a typical RS-422 connection for transmitting and receiving data.



Figure 13. Differential Power-Up Glitch (1V/µs)

Table 1. MAX3030E/MAX3031E Transmitter Controls

EN	ĒN	TX1	TX2	ТХЗ	TX4	MODE
0	0	Active	Active	Active	Active	All transmitters active
0	1	High-Z	High-Z	High-Z	High-Z	All transmitters disabled
1	0	Active	Active	Active	Active	All transmitters active
1	1	Active	Active	Active	Active	All transmitters active

Table 2. MAX3032E/MAX3033E Transmitter Controls

EN1&2	EN3&4	TX1	TX2	ТХЗ	TX4	MODE
0	0	High-Z	High-Z	High-Z	High-Z	All transmitters disabled
0	1	High-Z	High-Z	Active	Active	Tx 3 and 4 active
1	0	Active	Active	High-Z	High-Z	Tx 1 and 2 active
1	1	Active	Active	Active	Active	All transmitters active





Figure 14. Typical Connection of a Quad Transmitter and Quad Receiver as a Pair



Figure 15. MAX3030E/MAX3031E Functional Diagram





Chip Information

TRANSISTOR COUNT: 1050 PROCESS: BICMOS

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)





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